

# **PBSS5320T-QR Datasheet**

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iGi Electronics Part Number	PBSS5320T-QR-DG
Manufacturer	Nexperia USA Inc.
nufacturer Product Number	PBSS5320T-QR
Description	PBSS5320T-Q/SOT2
Detailed Description	Bipolar (BJT) Transis W Surface Mount TC

A Inc. QR Q/SOT23/TO-236AB

Transistor PNP 20 V 2 A 100MHz 300 m lount TO-236AB

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# Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
PBSS5320T-QR	Nexperia USA Inc.
Series:	Product Status:
-	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	2 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
20 V	300mV @ 300mA, 3A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ lc, Vce:
100nA (ICBO)	220 @ 500mA, 2V
Power - Max:	Frequency - Transition:
300 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
TO-236-3, SC-59, SOT-23-3	ТО-236АВ

## **Environmental & Export classification**

RoHS Status:	REACH Status:
ROHS3 Compliant	REACH Unaffected
ECCN:	HTSUS:
EAR99	8541.21.0075



# PBSS5320T-Q

20 V, 3 A PNP low VCEsat transistor

21 June 2022

**Product data sheet** 

## 1. General description

PNP low  $V_{CEsat}$  transistor in in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4320T

## 2. Features and benefits

- Low collector-emitter saturation voltage V<sub>CEsat</sub> and corresponding low R<sub>CEsat</sub>
- High collector current capability
- High collector current gain
- Improved efficiency due to reduced heat generation
- · Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Power management applications
- · Low and medium power DC/DC convertors
- Supply line switching
- Battery chargers
- Linear voltage regulation with low voltage drop-out (LDO).

## 4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	-20	V
I <sub>C</sub>	collector current		-	-	-2	А
I <sub>CRM</sub>		$\delta \le 0.25$ ; Operated under pulsed conditions; $t_p \le 100$ ms	-	-	-3	A
R <sub>CEsat</sub>	collector-emitter saturation resistance	I <sub>C</sub> = -2 A; I <sub>B</sub> = -200 mA; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-	75	105	mΩ

# nexperia

## 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	E	emitter		С
3	С	collector		B E sym132

## 6. Ordering information

#### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PBSS5320T-Q	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23			

## 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PBSS5320T-Q	ZH%

[1] % = placeholder for manufacturing site code

## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-20	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-20	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	-5	V
I <sub>C</sub>	collector current			-	-2	А
I <sub>CRM</sub>	repetitive peak collector current	$\delta \le 0.25$ ; Operated under pulsed conditions; $t_p \le 100$ ms		-	-3	A
I <sub>CM</sub>	peak collector current	single pulse; t <sub>p</sub> ≤ 1 ms		-	-5	А
I <sub>B</sub>	base current			-	-0.5	А
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	300	mW
			[2]	-	480	mW
			[3]	-	540	mW
			[1] [4]	-	1.2	W
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-65	150	°C

# PBSS5320T-Q

#### 20 V, 3 A PNP low VCEsat transistor

Symbol	Parameter	Conditions	Min	Max	Unit
T <sub>stg</sub>	storage temperature		-65	150	°C

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Operated under pulsed conditions: pulse width  $t_p \le 100$  ms; duty cycle  $\delta \le 0.25$ .

## 9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance from junction to ambient	thermal resistance from	in free air	[1]	-	-	417	K/W
	junction to ambient [2]	[2]	-	-	260	K/W	
		-	-	230	K/W		
			[1] [4]	-	-	104	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[4] Operated under pulsed conditions: pulse width  $t_p \le 100$  ms; duty cycle  $\delta \le 0.25$ .

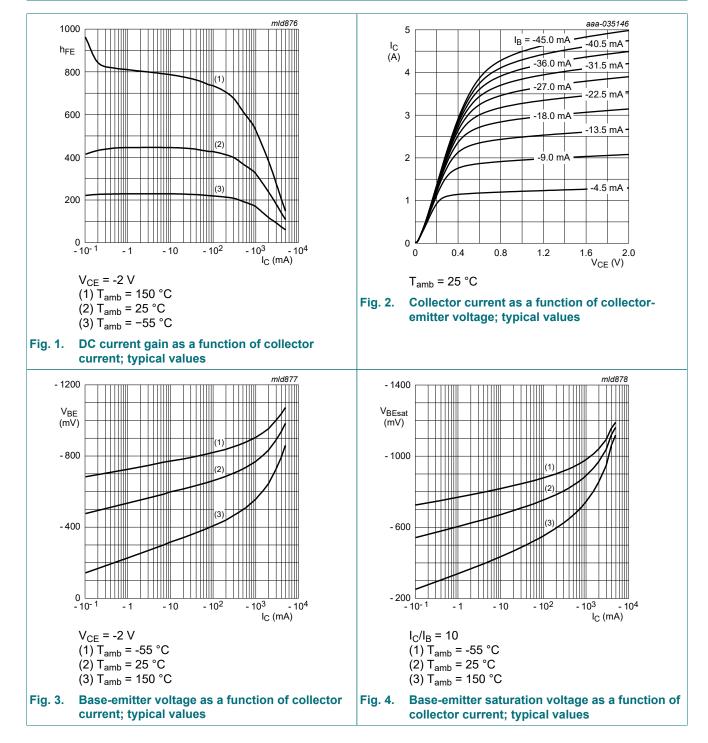
## **10. Characteristics**

#### Table 7. Characteristics Conditions Unit Symbol Parameter Min Max Тур V<sub>CB</sub> = -20 V; I<sub>E</sub> = 0 A; T<sub>amb</sub> = 25 °C collector-base cut-off -100 nA I<sub>CBO</sub> current V<sub>CB</sub> = -20 V; I<sub>E</sub> = 0 A; T<sub>i</sub> = 150 °C -50 uА V<sub>EB</sub> = -5 V; I<sub>C</sub> = 0 A; T<sub>amb</sub> = 25 °C emitter-base cut-off -100 I<sub>EBO</sub> nA current V<sub>CE</sub> = -2 V; I<sub>C</sub> = -100 mA; T<sub>amb</sub> = 25 °C DC current gain 220 h<sub>FF</sub> V<sub>CE</sub> = -2 V; I<sub>C</sub> = -500 mA; T<sub>amb</sub> = 25 °C 220 $V_{CE}$ = -2 V; I<sub>C</sub> = -1 A; pulsed; t<sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02; T<sub>amb</sub> = 25 °C 200 $V_{CE}$ = -2 V; I<sub>C</sub> = -2 A; pulsed; t<sub>p</sub> ≤ 300 µs; $\delta$ ≤ 0.02; T<sub>amb</sub> = 25 °C 150 $V_{CE}$ = -2 V; $I_C$ = -3 A; pulsed; $t_p \le$ 100 $300 \ \mu s; \delta ≤ 0.02; T_{amb} = 25 \ °C$ I<sub>C</sub> = -500 mA; I<sub>B</sub> = -50 mA; T<sub>amb</sub> = 25 °C collector-emitter -70 mV VCEsat saturation voltage I<sub>C</sub> = -1 A; I<sub>B</sub> = -50 mA; T<sub>amb</sub> = 25 °C -130 mV $I_C$ = -2 A; $I_B$ = -100 mA; pulsed; $t_p \le$ -230 mV 300 μs; $\delta \le 0.02$ ; T<sub>amb</sub> = 25 °C $I_{\rm C}$ = -2 A; $I_{\rm B}$ = -200 mA; pulsed; $t_{\rm p} \leq$ -210 mV \_ 300 μs; δ ≤ 0.02; T<sub>amb</sub> = 25 °C $I_{\rm C}$ = -3 A; $I_{\rm B}$ = -300 mA; pulsed; $t_{\rm p} \leq$ -300 mV 300 μs; δ ≤ 0.02; T<sub>amb</sub> = 25 °C R<sub>CEsat</sub> collector-emitter $I_{C}$ = -2 A; $I_{B}$ = -200 mA; pulsed; $t_{p} \le$ 75 105 mΩ saturation resistance 300 μs; $\delta \le 0.02$ ; T<sub>amb</sub> = 25 °C base-emitter saturation $I_{C}$ = -2 A; $I_{B}$ = -100 mA; pulsed; $t_{p} \le$ -1.1 v **V**<sub>BEsat</sub> 300 μs; δ ≤ 0.02; T<sub>amb</sub> = 25 °C voltage $I_{C}$ = -3 A; $I_{B}$ = -300 mA; pulsed; $t_{p} \leq$ V -1.2 300 μs; $\delta \le 0.02$ ; T<sub>amb</sub> = 25 °C

## PBSS5320T-Q

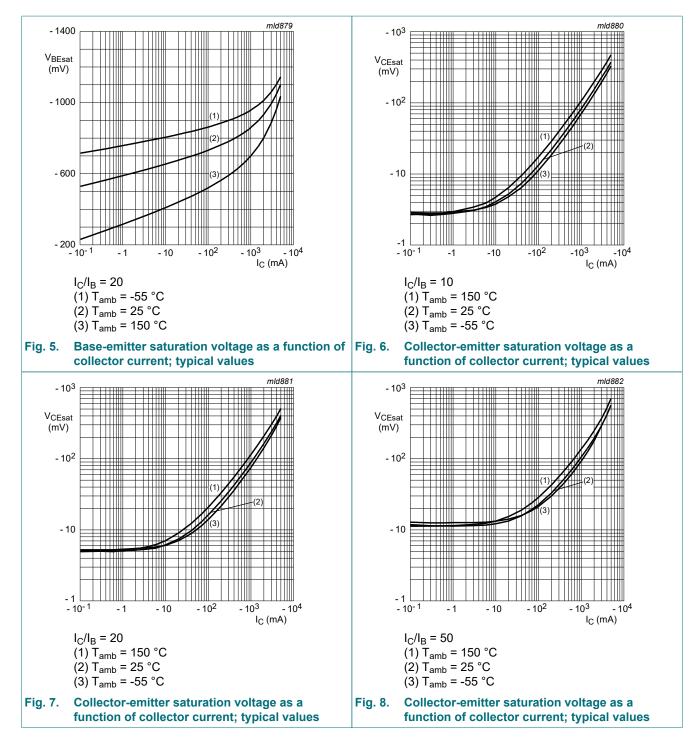
#### 20 V, 3 A PNP low VCEsat transistor

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>BEon</sub>	base-emitter turn-on voltage	$V_{CE}$ = -2 V; I <sub>C</sub> = -1 A; pulsed; t <sub>p</sub> ≤ 300 μs; δ ≤ 0.02; T <sub>amb</sub> = 25 °C	-1.2	-	-	V
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; I <sub>C</sub> = -100 mA; f = 100 MHz; T <sub>amb</sub> = 25 °C	100	-	-	MHz
C <sub>c</sub>	collector capacitance	V <sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C	-	-	50	pF



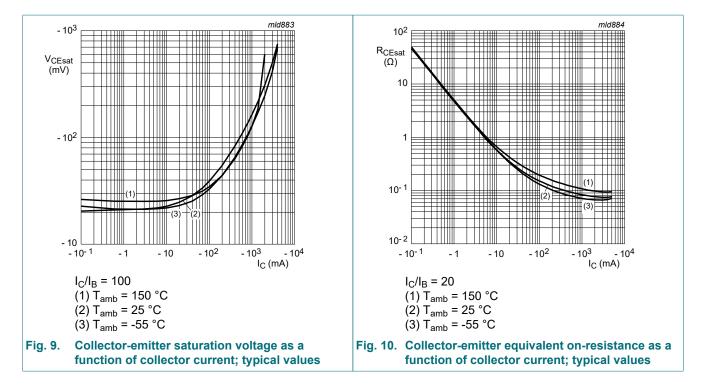
## PBSS5320T-Q

#### 20 V, 3 A PNP low VCEsat transistor



## PBSS5320T-Q

#### 20 V, 3 A PNP low VCEsat transistor

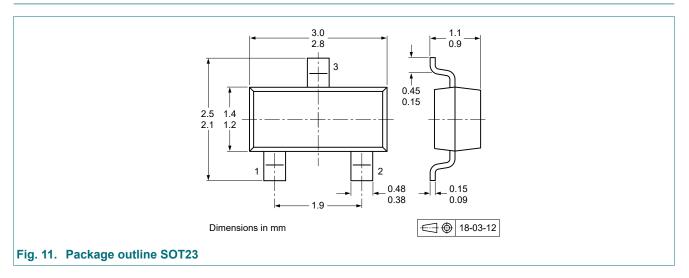


## **11. Test information**

#### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

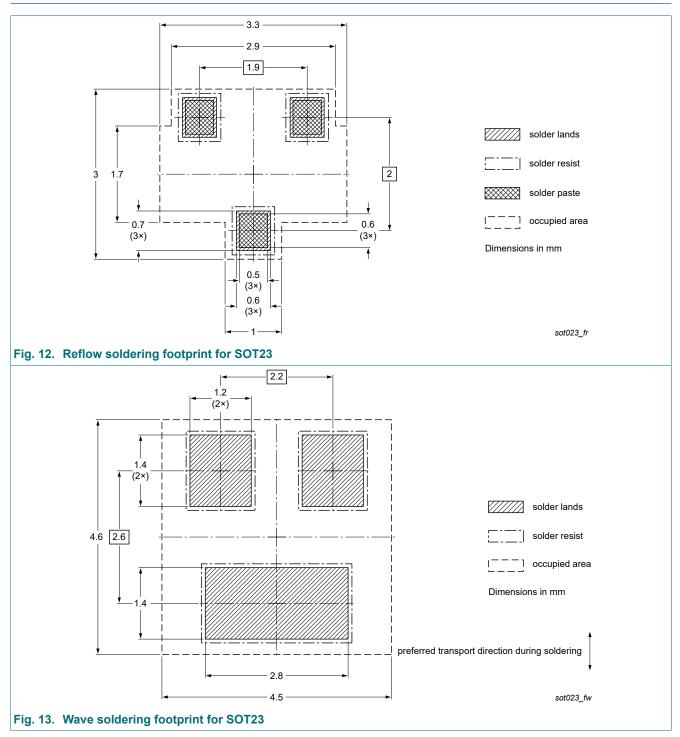
## **12. Package outline**



## PBSS5320T-Q

#### 20 V, 3 A PNP low VCEsat transistor

# 13. Soldering



PBSS5320T-Q

### 20 V, 3 A PNP low VCEsat transistor

# 14. Revision history

Table 8. Revision history								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PBSS5320T-Q v.2	20220621	Product data sheet	-	PBSS5320T-Q v.1				
Modifications:	Characteristics:	Characteristics: Figure 2 added						
PBSS5320T-Q v.1	20220505	Product data sheet	-	-				

PBSS5320T-Q

## PBSS5320T-Q

#### 20 V, 3 A PNP low VCEsat transistor

## 15. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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### 20 V, 3 A PNP low VCEsat transistor

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